NSN 5961-01-293-2058 Thyristor Semiconductor Device - Page 1 of 1



| View Online at https://aerobasegroup.com/nsn/5961-01-293-2058   |
|---|
| Inclosure Material:   |
| Metal   |
| Overall Length:   |
| 1.587 inches  |
| Mounting Facility Quantity:   |
| 1   |
| Mounting Method:  |
| Threaded stud   |
| Overall Width Across Flats:   |
| Between 0.552 inches and 0.562 inches   |
| Thread Size:  |
| 0.250 inches  |
| Semiconductor Material:   |
| Silicon   |
| Voltage Rating In Volts Per Characteristic:   |
| 200.0 repetitive peak off-state voltage and 600.0 repetitive peak off-state voltage and 200.0 repetitive peak reverse voltage and 600.0 |
| repetitive peak reverse voltage   |
| Current Rating Per Characteristic:  |
| 6.00 amperes forward current, total rms horsepower metric and 50.00 milliamperes forward current, total rms absolute                    |
| Maximum Operating Tempurature Per Measurement Point:  |
| 100.0 degrees celsius junction  |
| Thread Series Designator:   |
| Unf   |
| Terminal Type And Quantity:   |
| 1 threaded stud and 2 tab, solder lug   |
| Shelf Life:   |
| N/a   |
| Unit Of Measure:  |
| <del>-</del>  |
| Demilitarization:   |
| No  |
| Fiig:   |
| A110a0  |
|   |